

**SMA Schottky Barrier Rectifier Diode 肖特基势垒整流二极管**

■ **Features 特点**

Low forward voltage drop 低正向压降  
High current capability 高电流能力  
Surface mount device 表面贴装器件  
Case 封装:SMA(DO-214AC)



■ **Maximum Rating 最大额定值**

( $T_A=25^{\circ}\text{C}$  unless otherwise noted 如无特殊说明, 温度为  $25^{\circ}\text{C}$ )

Characteristic 特性参数	Symbol 符号	SS24LA	Unit 单位
Peak Reverse Voltage 反向峰值电压	$V_{RRM}$	40	V
DC Reverse Voltage 直流反向电压	$V_R$	40	V
RMS Reverse Voltage 反向电压均方根值	$V_{R(RMS)}$	28	V
Forward Rectified Current 正向整流电流	$I_F$	2	A
Peak Surge Current 峰值浪涌电流	$I_{FSM}$	50	A
Thermal Resistance J-A 结到环境热阻	$R_{\theta JA}$	88	$^{\circ}\text{C}/\text{W}$
Junction Temperature 结温	$T_J$	125	$^{\circ}\text{C}$
Storage Temperature 储藏温度	$T_{stg}$	-55to+150 $^{\circ}\text{C}$	$^{\circ}\text{C}$

■ **Electrical Characteristics 电特性**

( $T_A=25^{\circ}\text{C}$  unless otherwise noted 如无特殊说明, 温度为  $25^{\circ}\text{C}$ )

Characteristic 特性参数	Symbol 符号	SS24LA	Unit 单位	Condition 条件
Forward Voltage 正向电压	$V_F$	0.46	V	$I_F=2\text{A}$
Reverse Current 反向电流	$I_R(25^{\circ}\text{C})$ $(125^{\circ}\text{C})$	0.2 50	mA	$V_R=V_{RRM}$
Diode Capacitance 二极管电容	$C_D$	170	pF	$V_R=4\text{V}, f=1\text{MHz}$

■ Typical Characteristic Curve 典型特性曲线

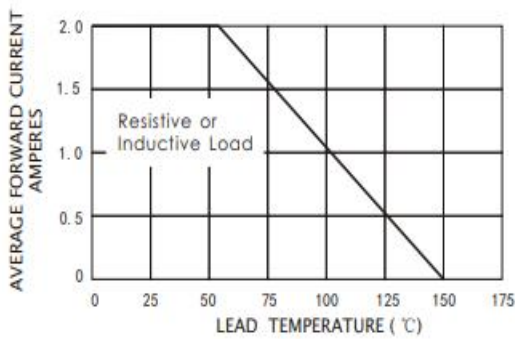


Figure 1: Forward Current Curve

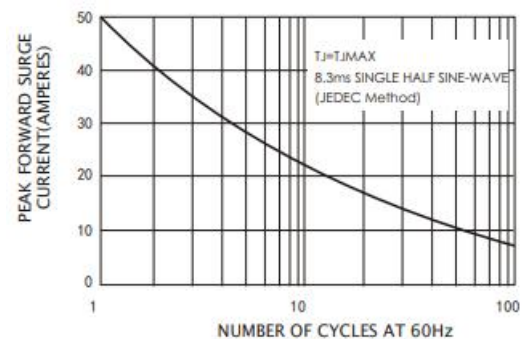


Figure 2: Forward Surge Current Curve

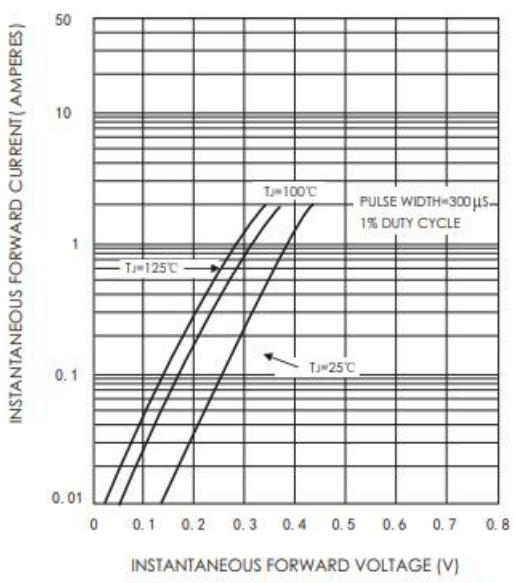


Figure 3: Forward Characteristics

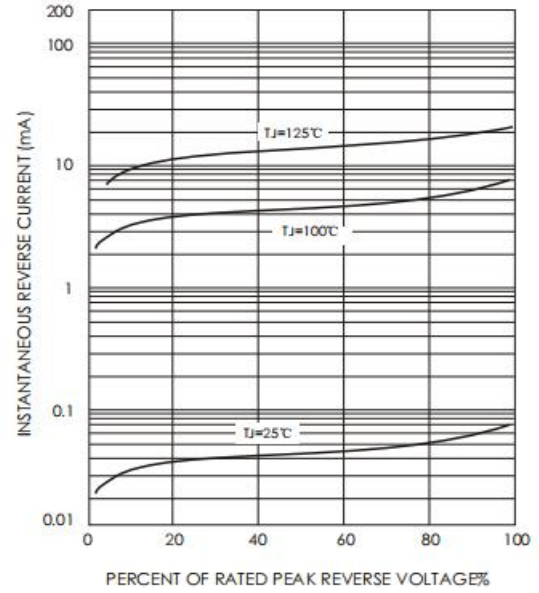


Figure 4: Reverse Characteristics

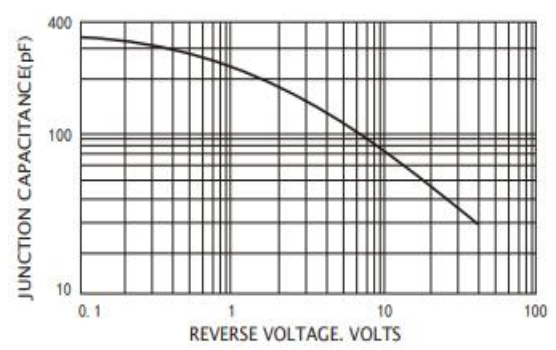
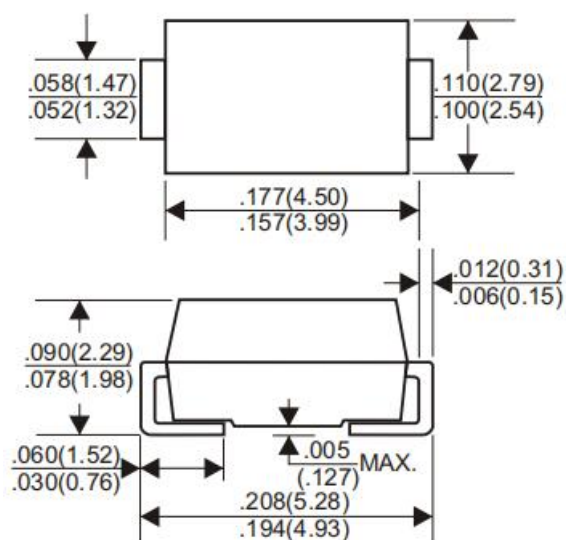


Figure 5: Capacitance Characteristics

■Dimension 外形封装尺寸

DO-214AC(SMA)



Dimensions in inches and (millimeters)